

#### **Features**

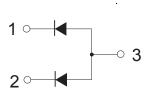
- Low forward voltage
- Fast reverse recovery time
- Small total capacitance



**SOT-23** 

## **Package Marking and Ordering Information**

Product ID	Pack	Marking	Qty(PCS)
1SS226	SOT-23	C3	3000



Maxmim Ratings (Ta=25 unless otherwise noted)

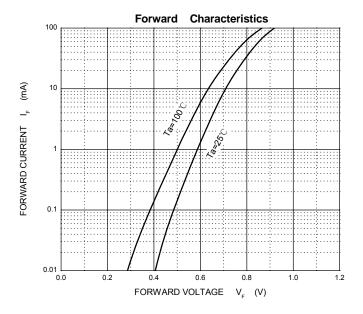
Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	$V_{RM}$	85	V
Peak Repetitive Peak Reverse Voltage	$V_{RRM}$		
Working Peak Reverse Voltage	$V_{RWM}$	80	V
DC Blocking Voltage	$V_{R}$		
Forward Continuous Current	$I_{FM}$	300	mA
Average Rectified Output Current	I <sub>O</sub>	100	mA
Non-Repetitive Peak Forward Surge Current @t=8.3ms	I <sub>FSM</sub>	2	А
Power Dissipation	$P_D$	150	mW
Thermal Resistance from Junction to Ambient	$R_{ heta JA}$	833	°C/W
Junction Temperature	T <sub>J</sub>	150	℃
Storage Temperature	T <sub>STG</sub>	-55~+150	°C

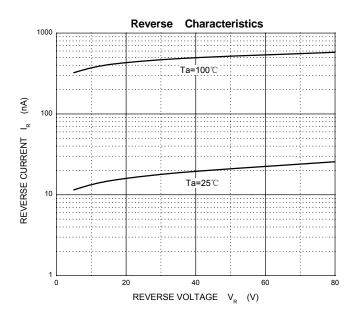
#### Electrcal Charcteristics (Ta=25 unless otherwise specified)

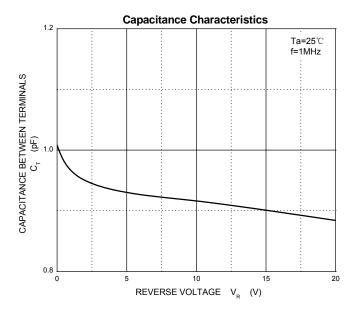
Licensel Characteristics (Ta 20 amoss otherwise specifica)					
Parameter	Symbol	Test conditions	Min	Max	Unit
Reverse breakdown voltage	$V_{(BR)}$	I <sub>R</sub> = 100uA	80		V
Reverse voltage leakage current	I <sub>R</sub>	V <sub>R</sub> =80V		0.5	uA
Forward voltage	$V_{F}$	I <sub>F</sub> =100mA		1.2	V
Diode capacitance	C <sub>D</sub>	V <sub>R</sub> =0V, f=1MHz		3	pF
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> =10mA		4	ns

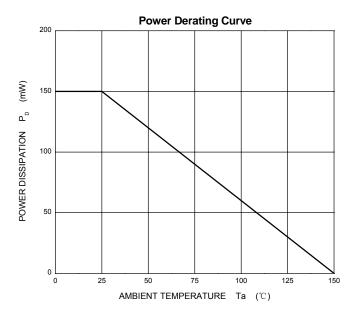


### **Typical Characteristics**

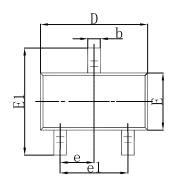


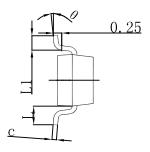


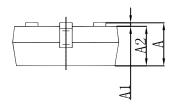




## **SOT-23 Package Outline Dimensions**

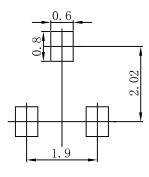






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
Е	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

# **SOT-23 Suggested Pad Layout**



- Note:
  1.Controlling dimension:in millimeters.
  2.General tolerance:± 0.05mm.
  3.The pad layout is for reference purposes only.



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